



P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	RDS(ON) MAX	ID MAX TA = +25°C	
-60V	55mΩ @ V _{GS} = -10V	-10.4A	
-00 V	80mΩ @ V _{GS} = -4.5V	-9.2A	

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Disconnect Switches
- Motor Control

Features and Benefits

- 100% Unclamped Inductive Switch (UIS) Test in Production
- Low On-Resistance
- Fast Switching Speed
- Low Threshold
- Low Gate Drive
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

https://www.diodes.com/products/automotive/automotive-products/.

 This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

https://www.diodes.com/quality/product-definitions/

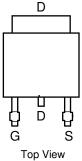
Mechanical Data

- Case: TO252
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Finish Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.33 grams (Approximate)

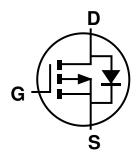
TO252 (DPAK)



Top View



Pin-Out



Equivalent Circuit

Ordering Information (Note 4)

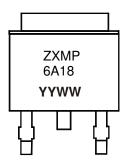
Part Number	Case	Packaging
ZXMP6A18KTC	TO252 (DPAK)	2,500/Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information



ZXMP6A18 = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 20 = 2020)WW = Week (01 to 53)

Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage		V _{DSS}	-60	V
Gate-Source Voltage		Vgss	±20	V
	T _A = +25°C (Note 6)		-10.4	А
Continuous Drain Current, VGS = -10V	T _A = +70°C (Note 6)	l _D	-8.3	
	T _A = +25°C (Note 5)		-6.8	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%) (Note 7)		I _{DM}	-37.5	Α
Maximum Body Diode Forward Current (Note 6)		ls	-10.4	Α
Pulsed Source Current (10µs Pulse, Duty Cycle = 1%) (Note 7)		Ism	-37.5	Α
Avalanche Current, L = 0.1mH		las	-36	Α
Avalanche Energy, L = 0.1mH		Eas	65	mJ

Thermal Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)		PD	4.3	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Rеја	29	°C/W
Total Power Dissipation (Note 6)	<u>.</u>	P _D	10.1	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	RеJA	12.3	°C/W
Total Power Dissipation (Note 8)		PD	2.15	W
Thermal Resistance, Junction to Case (Note 8)	Steady State	Rеја	58	°C/W
Operating and Storage Temperature Range	<u>.</u>	T _J , T _{STG}	-55 to +150	°C

5. For a device surface mounted on 50mm x 50mm x 1.6mm FR-4 PCB with high coverage of single sided 2oz copper, in still air conditions. Notes:

- 6. For a device surface mounted on FR-4 PCB measured at t <=10s.
- 7. Repetitive rating 50mm x 50mm x 1.6mm FR-4 PCB, D=0.02 pulse width=300s pulse width limited by maximum junction temperature.

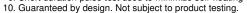
 8. For a device surface mounted on 25mm x 25mm x 1.6mm FR-4 PCB with high coverage of single sided 1oz copper, in still air conditions.

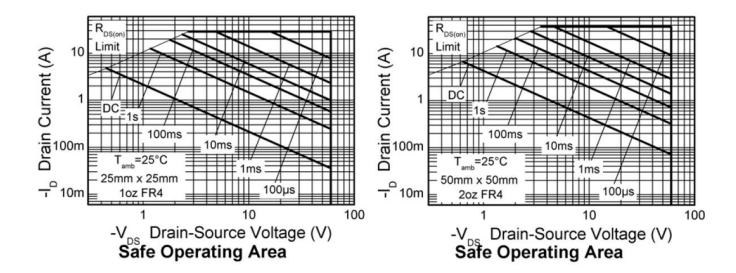


Electrical Characteristics (@ $T_A = +25$ °C, unless otherwise specified.)

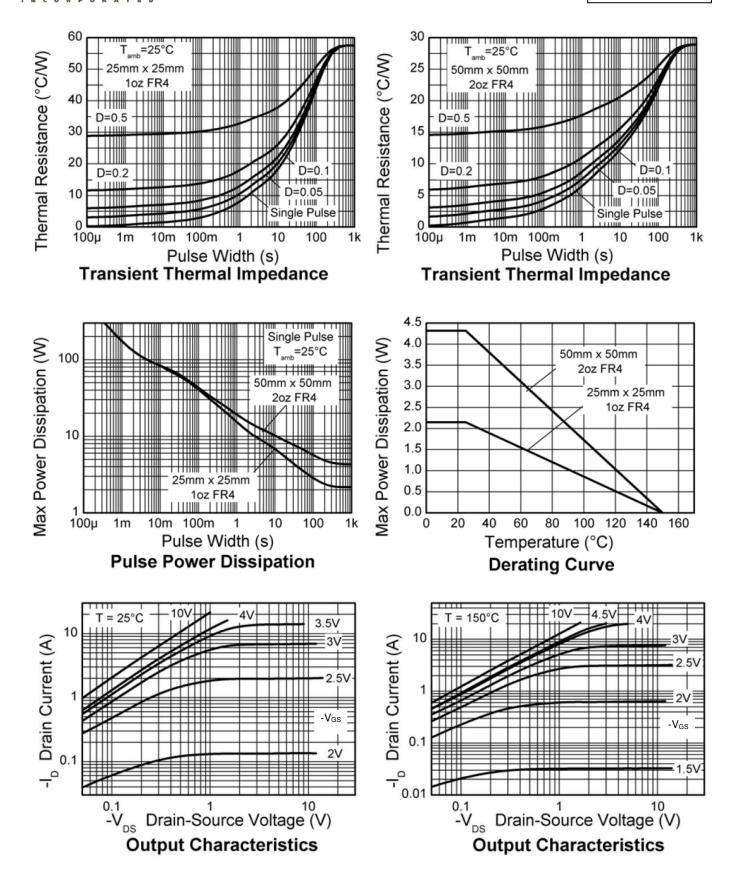
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)							
Drain-Source Breakdown Voltage	BVDSS	-60	_	_	V	$V_{GS} = 0V, I_{D} = -250\mu A$	
Zero Gate Voltage Drain Current	IDSS	_	_	-1	μΑ	$V_{DS} = -60V, V_{GS} = 0V$	
Gate-Source Leakage	IGSS	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)							
Gate Threshold Voltage	V _{GS(TH)}	-1.0	_	_	V	$V_{DS} = V_{GS}$, $I_D = -250\mu A$	
Static Drain-Source On-Resistance	Dagger		44	55	mΩ	$V_{GS} = -10V$, $I_{D} = -3.5A$	
Static Drain-Source On-Nesistance	Rds(on)	_	59	80	1115.2	$V_{GS} = -4.5V$, $I_{D} = -2.9A$	
Forward Transconductance	g _{fs}	_	8.7	_	S	$V_{DS} = -15V, I_{D} = -3.5A$	
Diode Forward Voltage	V _{SD}	_	-0.85	-0.95	V	Vgs = 0V, Is = -4.2A	
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	Ciss		1580	_		$V_{DS} = -30V$, $V_{GS} = 0V$ f = 1MHz	
Output Capacitance	Coss	_	160	_	pF		
Reverse Transfer Capacitance	Crss	_	140	_			
Total Gate Charge (VGS = -5V)	Qg	_	23	_		V _{DS} = -30V, I _D = -3.5A	
Total Gate Charge (V _{GS} = -10V)	Q _G	_	44	_	nC		
Gate-Source Charge	Q _{GS}	_	3.9	_	IIC		
Gate-Drain Charge	QgD		9.8	_			
Turn-On Delay Time	t _{D(ON)}	_	4.6	_		Vgs = -10V, VDD = -30V,	
Turn-On Rise Time	tR	_	5.8	_			
Turn-Off Delay Time	tD(OFF)		55	_	ns	$R_g = 6\Omega$, $I_D = -1A$	
Turn-Off Fall Time	tF	_	23	_			
Reverse Recovery Time	trr	_	37	_	ns	Is = -2.1A, di/dt = -100A/μs	
Reverse Recovery Charge	Q _{RR}	_	56	_	nC	$I_S = -2.1A$, di/dt = -100A/ μ s	

Notes: 9. Short duration pulse test used to minimize self-heating effect.



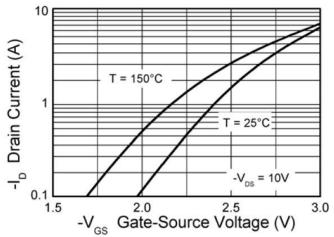






 $V_{GS} = -10\dot{V}$



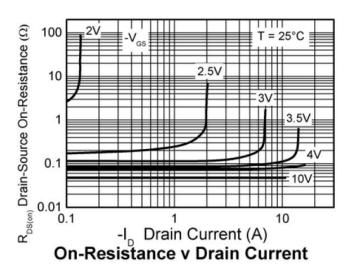


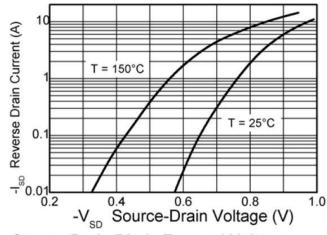
1.6 Note 1.4 Position Temperature (°C)

1.8

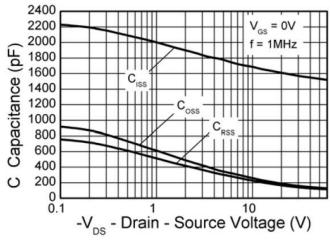
Typical Transfer Characteristics

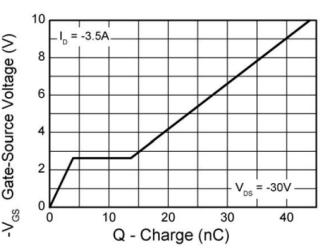






Source-Drain Diode Forward Voltage

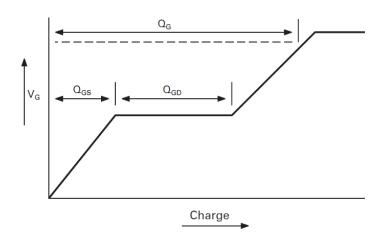




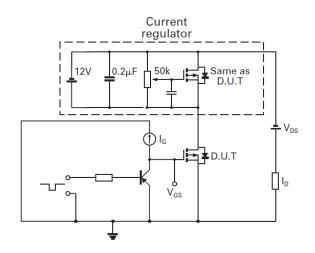
Capacitance v Drain-Source Voltage

Gate-Source Voltage v Gate Charge

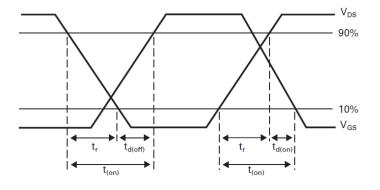




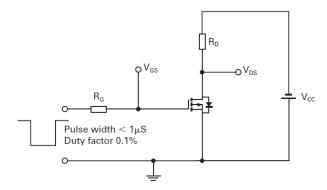
Basic gate charge waveform



Gate charge test circuit



Switching time waveforms



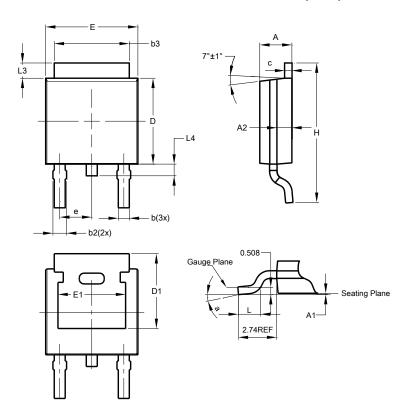
Switching time test circuit



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

TO252 (DPAK)

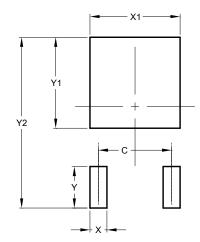


TO252 (DPAK)					
Dim	Min	Max	Тур		
Α	2.19	2.39	2.29		
A 1	0.00	0.13	0.08		
A2	0.97	1.17	1.07		
b	0.64	0.88	0.783		
b2	0.76	1.14	0.95		
b3	5.21	5.46	5.33		
С	0.45	0.58	0.531		
D	6.00	6.20	6.10		
D1	5.21	-	-		
е	-	-	2.286		
Е	6.45	6.70	6.58		
E1	4.32	-	-		
Н	9.40	10.41	9.91		
L	1.40	1.78	1.59		
L3	0.88	1.27	1.08		
L4	0.64	1.02	0.83		
а	0°	10°	-		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

TO252 (DPAK)



Dimensions	Value (in mm)			
С	4.572			
Х	1.060			
X1	5.632			
Υ	2.600			
Y1	5.700			
Y2	10.700			



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